# Determination of Cell Capacitance Using the Exact Empirical Solution of  $\partial Y/\partial C_m$  and Its Phase Angle

#### Joseph Santos-Sacchi

Otolaryngology and Neurobiology, Yale University School of Medicine, New Haven, Connecticut 06510

ABSTRACT Measures of membrane capacitance offer insight into a variety of cellular processes. Unfortunately, popular methodologies rely on model simplifications that sensitize them to interference from inevitable changes in resistive components of the traditional cell-clamp model. Here I report on a novel method to measure membrane capacitance that disposes of the usual simplifications and assumptions, yet is immune to such interference and works on the millisecond timescale. It is based on the exact empirical determination of the elusive partial derivative,  $\partial Y/\partial C_m$ , which heretofore had been approximated. Furthermore, I illustrate how this method extends to the vesicle fusion problem by permitting the determination of  $\partial Y_v/\partial C_v$ , thereby providing estimates of fusion pore conductance and vesicle capacitance. Finally, I provide simulation examples and physiological examples of how the method can be used to study processes that are routinely interrogated by measures of membrane capacitance.

### INTRODUCTION

Biological cells are typically modeled as simple parallel combinations of an electrical resistance and capacitance. Measures of membrane capacitance  $(C<sub>m</sub>)$  based on this model under voltage clamp provide an informative view of such varied processes as fertilization (Jaffe and Schlichter, 1985), ionic channel gating (Fernandez et al., 1982), synaptic vesicle fusion (Neher and Marty, 1982), gap junctional coupling (Santos-Sacchi, 1991a), and receptor cell activity (Zhao and Santos-Sacchi, 1999).

A powerful feature of capacitance measures is the ability to monitor interactions between membrane-bound compartments, e.g., fusion of vesicles with the plasma membrane or cell coupling via gap junctions (Neher and Marty, 1982; Joshi and Fernandez, 1988; Santos-Sacchi, 1991a; Zhao and Santos-Sacchi, 1998), because these measures provide an estimate of membrane surface area (Fricke, 1925; Cole, 1971). Indeed, electrical measures of vesicular fusion (Alvarez De Toledo et al., 1993) have played a significant role in the development of one of the most controversial issues facing neurobiology today, namely, the occurrence of kiss-and-run synaptic vesicle transmitter release (Gandhi and Stevens, 2003; Aravanis et al., 2003). Single-frequency admittance analysis of membrane fusion, pioneered by Neher and Marty (1982), has been used by a number of investigators to gauge the time course of vesicular membrane fusion by monitoring the changes in the conductance of the fusion pore that initiates membrane fusion (Breckenridge and Almers, 1987; Alvarez De Toledo et al., 1993; Debus and Lindau, 2000; Klyachko and Jackson, 2002). Estimates of the pore's initial conductance hover near single-channel

Submitted August 29, 2003, and accepted for publication March 8, 2004. Address reprint requests to Joseph Santos-Sacchi, E-mail: joseph. santos-sacchi@yale.edu.

 2004 by the Biophysical Society 0006-3495/04/07/714/14 \$2.00 doi: 10.1529/biophysj.103.033993

conductance values (Breckenridge and Almers, 1987; Lollike et al., 1995).

Arguably the most widely used method to measure membrane capacitance  $(C_m)$  is the phase-angle method, variously termed, but all employing approaches to extract the current at a particular phase angle arising from small changes in  $C_m$  (Neher and Marty, 1982; Gillis, 1995). Such AC methods ostensibly provide excellent time resolution and sensitivity. Multifrequency approaches, which we and others have used (Fernandez et al., 1982; Santos-Sacchi, 1989; Zhao and Santos-Sacchi, 1999), are less in vogue, but offer potential protection from changes in admittance that can plague single-sine methods. Implementations of step, single-, and dual-sine techniques are available in a few software packages (jClamp, www.SciSoftCo.com; pClamp, www. Axon.com; Pulse Control, www.Instrutech.com, chroma. med.miami.edu/cap).

One of the key problems that challenges the validity of  $C<sub>m</sub>$  measures, and thus our understanding of those cellular processes that are interrogated by  $C<sub>m</sub>$  measurements, is the interference of those measures by changes in either patch electrode resistance  $(R_s)$  or cell membrane resistance  $(R_m)$ , the latter often a natural corollary of those cellular processes (Gillis, 1995; Debus et al., 1995). An extensively discussed topic of the single-sine camp concerns the determination of the proper phase angle to utilize in measuring small changes in membrane capacitance. There are various mechanisms to determine an appropriate phase angle, but all estimates of capacitance employ simplifying assumptions and requirements, usually devised to limit the effects of uncontrollable  $R_s$  and  $R_m$  changes on  $C_m$  measures. Indeed, the traditional methodology of single-sine admittance analysis suffers from a number of assumptions and simplifications, especially those methods used to extract vesicle capacitance and conductance, and the fusion pore conductance. These

assumptions cannot be met in all cases, and this quandary is clearly indicated by the posthoc manipulations of data that are often required (Lindau, 1991; Ratinov et al., 1998). In detailing these assumptions, I refer to the traditional electrical circuit models that are used to evaluate admittance data (Fig. 1). A nearly universal assumption is that  $R_m \gg R_s$ ; additionally, for fusion vesicle analysis,  $R_v \gg R_p$ , and in some cases  $R_v = \infty$ . Below I illustrate through circuit analysis and modeling how these assumptions can lead to errors, and provide a method, based on the exact empirical identification of the partial derivatives  $\partial Y/\partial C_m$  and  $\partial Y_v$  $\partial C_{v}$ , that offers solutions without compromising assumptions. The approach is referred to as the  $eCm$  method.

## Theory

The phase of the capacitive current components evoked by a sinusoidal command voltage  $(V)$  across the simple models presented in Fig. 1 can be used to arrive at measures of the capacitive components themselves. Once the capacitive component values are obtained, the resistive component values are easily deduced. This can be appreciated from the



FIGURE 1 Circuit models. (A) The standard patch-clamp-cell model. Voltage (V) is set across the electrode  $(R_s)$  and cell membrane resistance  $(R<sub>m</sub>)$ —capacitance  $(C<sub>m</sub>)$ . The series components between headstage and ground,  $R_d$  and  $C_d$ , model the whole-cell capacitance compensation circuitry when connected. (B) A vesicle is fused with the plasma membrane.  $C_v$  is vesicle capacitance,  $R_p$  is fusion pore resistance, and  $R_v$  is vesicle resistance.

following evaluation, which first deals with the model without a fusion vesicle and without capacitance compensation components (Fig. 1 A).

Two standard conditions must be met for successful use of the methods detailed here: 1), the patch-clamp system transfer function (which derives from all equipment that contributes to shaping the output current) must be corrected for. This is a trivial matter, where a pure resistor, say 1  $\text{M}\Omega$ , is used at the input of the headstage to determine the correction phase and magnitude at each frequency (see Gillis, 1995 for details); and 2), the pipette stray capacitance must be neutralized before establishing whole-cell configuration.

### Absent vesicle fusion

The current measurable under voltage clamp (Fig. 1) is that through  $R_s$ , namely,  $I_{Rs}$ . According to Ohm's law,  $I_{Rs}$  is defined as the product of the clamp voltage  $(V)$  and input admittance  $(Y)$  of the circuit.

$$
I_{\text{Rs}} = \mathbf{Y}V = (\mathbf{A}_{\text{Y}} + j\mathbf{B}_{\text{Y}})V, \tag{1}
$$

where  $A_Y$  and  $B_Y$  are the real and imaginary components of the admittance. Closer inspection of the circuit reveals that  $I_{\text{Rs}}$  is the sum of a resistive and a capacitive component induced by only that portion  $(V_m)$  of the clamp voltage  $(V)$ , which drops across the cell membrane  $(R_m \parallel C_m)$ ,

$$
I_{\text{Rs}} = I_{\text{Rm}} + I_{\text{Cm}} = \frac{V_{\text{m}}}{R_{\text{m}}} + j\omega C_{\text{m}} V_{\text{m}}.
$$
 (2)

These equations show that  $I_{\text{Rs}}$  can be represented as a frequency ( $\omega = 2\pi f$ ) dependent complex number,

$$
\mathbf{Y}_{\mathrm{m}} = \frac{(\mathbf{A}_{\mathrm{I}_{\mathrm{R}s}} + j\mathbf{B}_{\mathrm{I}_{\mathrm{R}s}})}{V_{\mathrm{m}}},\tag{3}
$$

where  $Y_m$  is the membrane admittance,  $A_{Irs}$  is the real component, and  $\mathbf{B}_{\text{Irs}}$  is the imaginary component of  $I_{\text{Rs}}$ . Plainly, this signifies that the phase relationship between capacitive  $(I_{\text{Cm}})$  and resistive  $(I_{\text{Rm}})$  membrane current components is 90°. It is important to realize that the magnitude of the series resistance  $(R_s)$ , or its existence (i.e.,  $R_s = 0$ ), is irrelevant, and will not affect the phase relationship between  $I_{\text{Cm}}$  and  $I_{\text{Rm}}$ . Of course, for  $R_s > 0$ , the phase of  $I_{\text{Rs}}$ , relative to that of V, will vary as a result of any circuit parameter change, because the phase of  $I_{\text{Rs}}$  is dependent on that of  $V_{\text{m}}$ ,

$$
\angle V_{\rm m} = -\tan^{-1}(\omega \tau_{\rm clamp}),\tag{4}
$$

where  $\tau_{\text{clamp}}$ , the actual clamp time constant, is

$$
\tau_{\text{clamp}} = R_{\parallel} C_{\mathrm{m}} = \frac{R_{\mathrm{s}} R_{\mathrm{m}}}{R_{\mathrm{s}} + R_{\mathrm{m}}} C_{\mathrm{m}} = \frac{R_{\mathrm{s}} R_{\mathrm{m}}}{R_{\mathrm{m}}} C_{\mathrm{m}}.
$$
 (5)

Viewed relative to the phase of the command voltage  $(V)$ , the capacitive current phase angle,  $\Phi$ , will always reside at

$$
\Phi = \angle V_{\text{m}} + 90^{\circ} = \angle I_{\text{Rm}} + 90^{\circ}
$$
  
=  $-\tan^{-1}(\omega \tau_{\text{clamp}}) + 90^{\circ}.$  (6)

Thus, in the absence of  $R_s$  ( $R_s = 0$ ), the angles of  $V_m$  and V are identical, and  $\Phi$  will be orthogonal to the angle of V. However, as pointed out by Neher and Marty (1982), the introduction of  $R_s$  causes  $\Phi$  to shift away from orthogonality with respect to the applied command voltage  $(V)$ . The phase shift,  $\theta$ , in the angle of  $I_{\text{Rs}}$  that accompanies changes in the circuit parameters is defined as

$$
\theta = \angle V_{\rm m} - \angle I_{\rm Rs} = \angle I_{\rm Rm} - \angle I_{\rm Rs}
$$
  
=  $-\tan^{-1}(\omega R_{\rm m} C_{\rm m}),$  (7)

and thus

$$
\Phi = \angle I_{\text{Rs}} + \theta + 90^{\circ}.
$$
 (8)

Although it is apparent from Eq. 2 that the magnitude of the current at  $\Phi$ , namely,  $I_{\text{Cm}}$ , can be used to extract  $C_{\text{m}}$ 

$$
|I_{\rm Cm}| = \text{Re}(I_{\rm Rs}e^{-j\Phi})\tag{9}
$$

$$
C_{\rm m} = \frac{I_{\rm cm}}{j\omega V_{\rm m}} = \frac{|I_{\rm cm}|}{\omega |V_{\rm m}|},\tag{10}
$$

neither absolute angle,  $\theta$  nor  $\Phi$ , can be determined from direct manipulation of the empirically obtained input admittance at any one frequency. Thus, in the face of changing circuit parameters, estimating  $C<sub>m</sub>$  by directly measuring raw current at  $\Phi$  appears unfeasible. Nevertheless, inspection of the current at  $\Phi$  can be achieved by operating on the imaginary component of  $I_{\text{Rs}}$ , whose phase follows those phase shifts that result from parameter changes.

$$
I_{\rm Cm} = \text{conj}\left[\frac{\mathbf{B}_{\rm I_{\rm RS}}V}{j\ V_{\rm m}}\right].\tag{11}
$$

Thus, the imaginary component of Y (or  $I_{\text{Rs}}$ ) can be used to find  $C_m$ . To obtain direct estimates of  $C_m$  from  $\mathbf{B}_Y$ , one needs to correct  $\mathbf{B}_{\rm Y}$  with a noncomplex gain factor  $(H_c)$  that accounts for the relationship between inevitable changes in  $R_s$ ,  $R<sub>m</sub>$ , and  $C<sub>m</sub>$  that occur during the course of an experiment.

$$
C_{\rm m} = H_{\rm c} \mathbf{B}_{\rm Y},\tag{12}
$$

where, after substitution and rearrangement,

$$
H_{\rm c} = \frac{(1 + \omega^2 \tau_{\rm clamp}^2)}{\omega \left[ 1 - \frac{\tau_{\rm clamp}}{\tau_{\rm cell}} \right]^2},\tag{13}
$$

and

$$
\tau_{\text{cell}} = R_{\text{m}} C_{\text{m}}.\tag{14}
$$

Note that  $\tau_{cell}$  is the membrane time constant, and most importantly,

$$
H_{\rm c}^{-1} = abs(\partial \mathbf{Y}/\partial C_{\rm m}).\tag{15}
$$

Thus, to extract  $C_m$  from  $\mathbf{B}_Y$ , we must precisely evaluate the partial derivative,  $\partial Y/\partial C_{\text{m}}$ . This is one of the enigmas facing cell capacitance aficionados.

There are two methods that are routinely used to provide estimates of  $\partial Y/\partial C_m$  and its phase angle; both involve dithering of circuit parameters, and typically require hardware modifications and/or manipulations (Fidler and Fernandez, 1989; Joshi and Fernandez, 1988; Neher and Marty, 1982). Series resistance dithering and capacitance compensation dithering each have shortcomings that have been discussed in detail (Joshi and Fernandez, 1988). Ultimately, these shortcomings stem from the untoward effects of series resistance, because as  $R_m/R_{in} \rightarrow 1$ , the circuit of Fig. 1 A approaches a simple parallel  $R<sub>m</sub>$  C<sub>m</sub> configuration, and the estimates ultimately provide precise solutions. Regrettably, we are rarely so lucky during our experimental manipulations of cells to guarantee such relationships (Debus et al., 1995). Can this problem be resolved? That is, can the true magnitude and phase angle of  $\partial$ **Y**/ $\partial$ C<sub>m</sub> be obtained, so that estimates of C<sub>m</sub> are impervious to cell and clamp parameter changes? Furthermore, can this be accomplished without hardware additions and manipulations? Actually, it is a simple task, requiring, in addition to measures of  $\mathbf{B}_{Y}$ , the determination of the partial derivative,  $\frac{\partial \mathbf{Y}}{\partial \omega}$  or correspondingly,  $\frac{\partial I_{\text{Rs}}}{\partial \omega}$ . As we shall see, such a determination ensures accurate measures of membrane capacitance.

$$
\frac{\partial Y}{\partial \omega} = \alpha_{\omega} e^{j\beta_{\omega}},\tag{16}
$$

where the magnitude  $(\alpha_{\omega})$  and phase  $(\beta_{\omega})$  are

$$
\alpha_{\omega} = \frac{\mathbf{B}_{\mathrm{Y}}}{\omega} \tag{17}
$$

$$
\beta_{\omega} = -\tan^{-1} \left[ \frac{\omega^2 \tau_{\text{clamp}}^2 - 1}{2\omega \tau_{\text{clamp}}} \right]. \tag{18}
$$

Significantly,  $\beta_{\omega}$ , the phase angle of  $\partial I_{\text{Rs}}/\partial \omega$  and  $\partial \mathbf{Y}/\partial \omega$ , is identical to that of  $\partial Y/\partial C_m$ , and also to the angle of  $\partial Y/\partial R_{\rm m}$  + 90°. This can be appreciated immediately by inspection of the partial derivatives.

$$
\partial \mathbf{Y} / \partial \omega = \frac{\mathbf{Y}^2}{\mathbf{Y}_m^2} j C_m \tag{19}
$$

$$
\partial \mathbf{Y} / \partial C_{\mathfrak{m}} = \frac{\mathbf{Y}^2}{\mathbf{Y}_{\mathfrak{m}}^2} j\omega
$$
 (20)

$$
\partial \mathbf{Y} / \partial R_{\mathbf{m}} = -\frac{\mathbf{Y}^2}{\mathbf{Y}_{\mathbf{m}}^2} \frac{1}{R_{\mathbf{m}}^2},\tag{21}
$$

where

$$
\frac{1}{\mathbf{Y}_{\mathrm{m}}} = \frac{1}{\mathbf{Y}} - \frac{1}{G_{\mathrm{s}}} = \frac{1}{\mathbf{Y}} - R_{\mathrm{s}}.
$$
 (22)

It is this equivalence between the angles of  $\partial Y/\partial \omega$  and  $\partial Y/\partial C_m$  that forms the basis of the new *eCm* method of capacitance measurement that I report here. Given the angle,  $\beta_{\omega}$ , and the real and imaginary components of Y, the two time constants,  $\tau_{\text{clamp}}$  and  $\tau_{\text{cell}}$ , can be found. Each has two solutions, one of which will be realizable (positive) depending on the circuit parameters. For subsequent calculations the positive values must be used.

$$
\tau_{\text{clamp}} = \left[ -\tan(\beta_{\omega}) \pm \sqrt{1 + \tan(\beta_{\omega})^2} \right] \omega^{-1} \qquad (23)
$$

$$
\tau_{\text{cell}} = \frac{1 - \omega^2 \tau_{\text{clamp}}^2 - 2\eta \omega \tau_{\text{clamp}} \pm c}{\omega(-\eta + \eta \omega^2 \tau_{\text{clamp}}^2 - 2\omega \tau_{\text{clamp}})}
$$
(24)

where

$$
c = \left[ \sqrt{1 + \eta^2} + \sqrt{1 + \eta^2} \omega^2 \tau_{\text{clamp}}^2 \right] \tag{25a}
$$

$$
\eta = \tan \left[ 2 \tan^{-1} \left( \frac{\mathbf{B}_{Y}}{\mathbf{A}_{Y}} \right) \right] = \tan (\angle \partial \mathbf{Y} / \partial G_{s}). \tag{25b}
$$

Finally, with  $\tau_{\text{clamp}}$  and  $\tau_{\text{cell}}$  in hand,  $H_c$  (Eqs. 13 and 15) can be obtained, thus revealing the exact solution for all clamp parameters,  $R_s$ ,  $R_m$ , and  $C_m$ .

$$
C_{\rm m} = \mathbf{B}_{\rm Y} H_{\rm c} = \frac{\mathbf{B}_{\rm Y}}{|\partial \mathbf{Y}/\partial C_{\rm m}|} = \mathbf{B}_{\rm Y} \frac{(1 + \omega^2 \tau_{\rm clamp}^2)}{\omega \left[1 - \frac{\tau_{\rm clamp}}{\tau_{\rm cell}}\right]^2}
$$
(26)  

$$
R_{\rm m} = \frac{\tau_{\rm cell}}{C_{\rm m}}
$$
(27)

$$
R_{\rm s} = \frac{-\tau_{\rm clamp} \tau_{\rm cell}}{C_{\rm m} (\tau_{\rm clamp} - \tau_{\rm cell})}.
$$
 (28)

For completeness, the pertinent partial derivatives are provided in polar form (all parameters obtainable through a combination of measurement (that of Y and  $\beta_{\omega}$ ; see following) and calculation (as above)),

$$
\partial \mathbf{Y} / \partial C_{\mathbf{m}} = H_{\mathbf{c}}^{-1} e^{j\beta_{\omega}} = \frac{\omega \left[ 1 - \frac{\tau_{\text{clamp}}}{\tau_{\text{cell}}} \right]^2}{(1 + \omega^2 \tau_{\text{clamp}}^2)} e^{j\beta_{\omega}}.
$$
 (29)

$$
\partial \mathbf{Y} / \partial \omega = \frac{\mathbf{B}_{\mathrm{Y}}}{\omega} e^{j\beta_{\omega}}.
$$
 (30)

### The exact determination of  $\beta_{\omega}$

Several practical approaches to obtain  $\beta_{\omega}$  via frequency manipulations are available. Ordinarily, the empirical determination of an angle of a partial derivative with respect to angular frequency, such as  $\beta_{\omega}$ , is found by introducing a second voltage sinusoid  $(\omega_1)$ , in addition to the primary,  $\omega_0$ at an infinitesimal interval of  $d\omega$ , which must be approximated with  $\Delta\omega$ . The angle of the resulting difference current will closely approximate  $\beta_{\omega}$ . However, the determination of  $\beta_{\omega}$ using digital techniques necessitates that the two frequencies be no closer than the minimum frequency interval,  $\omega_{\min}$ . This interval is determined by the number of points (npts) of the stimulus ( $\omega_{\text{min}} = 1/(dt \text{ npts})$ , where  $dt =$  sample clock) (see Oppenheim and Schafer, 1975). Unfortunately, the rather large size of  $\omega_{\text{min}}$  offered by a stimulus composed of, say, 128 points at 4  $\mu$ s clock, will provide for a poor approximation of  $d\omega$  by  $\Delta\omega$  ( $f_{\text{min}}$  would be 1953.1 Hz). Of course, *npts* can be increased such that  $\omega_{\text{min}}$  would be very small and permit a reasonable approximation of  $\beta_{\omega}$ , but time resolution suffers. If high time resolution is not an issue, or if discrete determinations (as in ''pause and dither'' approaches) are acceptable, then determining the angle of the difference current at the primary frequency  $(\omega_0)$  and secondary frequency  $(\omega_1)$  at a very small interval will give  $\beta_{\omega}$ .

Alternatively, a nondiscrete hardware implementation of this technique could easily allow  $d\omega$  to be approached; furthermore, the magnitude of the second frequency could be quite small, because only the phase would be required. In fact, the stimulus could very well resemble a single sinusoid, thus limiting the cell's stimulus exposure.

Notwithstanding these approaches to the determination of  $\beta_{\omega}$ , our overriding intent is to obtain a method for  $C_{\rm m}$ measurement without additional hardware or hardware manipulations, and to correct for parameter changes on a point-by-point (real time) basis. To this end, it is fortuitous that the need for an infinitesimal interval,  $d\omega$ , can be circumvented by acknowledging that for the linear component model of Fig. 1  $a$ ,  $R_s$  or  $R_m$  may be considered frequency independent. That is, we may use either of the derivations of  $R_s$  or  $R_m$  provided by Pusch and Neher, 1988 (their Eqs. 5 and 6 reproduced below); also see Lindau and Neher (1988) to obtain an exact solution of  $\beta_{\omega}$  at  $\omega_0$ .

$$
R_{\rm s} = \frac{\mathbf{A}_{\omega n} - b}{\mathbf{A}_{\omega n}^2 + \mathbf{B}_{\omega n}^2 - \mathbf{A}_{\omega n} b}
$$
(31)

$$
R_{\rm m} = \frac{1}{b} \frac{(\mathbf{A}_{\omega \rm n} - b)^2 + \mathbf{B}_{\omega \rm n}^2}{\mathbf{A}_{\omega \rm n}^2 + \mathbf{B}_{\omega \rm n}^2 - \mathbf{A}_{\omega \rm n} b},\tag{32}
$$

where  $b = 1/(R_s + R_m)$  and  $n = 0,1$ .

Equating  $R_s$  (or  $R_m$ , either of which produce the exact same result) determined at two angular frequencies,  $\omega_0$  and  $\omega_1$ , provides two solutions for b  $(b_0, b_1;$  solutions not shown), and therefore two solutions for  $\tau_{\text{clamp}}$  at  $\omega_0$  (obtained by utilizing Pusch and Neher's (1988) solution for  $C_m$ ; their Eq. 7),

$$
\tau_{\text{clamp}_n} = \frac{\mathbf{A}_0 - b_n}{\mathbf{B}_0 \omega_0}.
$$
\n(33)

Notably, however, either solution of  $\tau_{\text{clamp}}$ ,  $\tau_{\text{clamp}_0}$ , or  $\tau_{\text{clamp}_1}$ , when used to derive the angle of  $\partial \mathbf{Y}/\partial \omega$ , i.e.,  $\beta_{\omega 0}$ , from Eq. 18 produces only one, unique result, namely

$$
\beta_{\omega 0} = \tan^{-1} \left[ \frac{1}{2} \frac{A_1^2 - 2A_1 A_0 + A_0^2 - B_0^2 + B_1^2}{B_0 (A_1 - A_0)} \right],
$$
 (34)

where the subscripts denote the real  $(A)$  and imaginary  $(B)$ admittance components at any two angular frequencies,  $\omega_0$  and  $\omega_1$ . It should be pointed out that whereas two frequencies are required to obtain  $\beta_{\omega}$ , the value itself is derived from  $\partial \mathbf{Y}/\partial \omega_0$ , whose location is exactly at  $\omega_0$ .

$$
d_{\omega}\mathbf{Y}/d\omega_0 = \lim_{\Delta\omega \to 0} \mathbf{Y}_{w_0 + \Delta\omega} - \mathbf{Y}_{w_0}
$$
 (35)

$$
\partial \mathbf{Y}/\partial \omega_0 \triangleq d_{\omega} \mathbf{Y}/d\omega_0, \tag{36}
$$

that is, all three pieces of information,  $\mathbf{B}_{\rm Y}$ ,  $\mathbf{A}_{\rm Y}$ , and  $\beta_{\omega}$  that are used to measure  $C_m$  theoretically derive from single  $(\omega_0)$ , not dual, frequency inspection.

# Present vesicle fusion

The fusion of independent membrane-bound compartments (vesicle to the plasma membrane or gap junctional coupling between two cells) can be evaluated with input capacitance measures, and modeled to obtain component values of the

applicable circuit (Fig. 1 B) (Zhao and Santos-Sacchi, 1998; Bigiani and Roper, 1995; Santos-Sacchi, 1991a). Below, I focus on vesicular fusion. If experiments are performed using the cell-attached mode it must be determined that the cell's input admittance is far greater than the patch admittance. Additionally, data must be corrected posthoc after determination of stray pipette capacitance (perhaps using the Sylgard bead-sealing technique (Sakmann and Neher, 1995)), which may be greater than patch capacitance. Thus, the application of this method under cell-attached mode is not straightforward. Nevertheless, in that case, or if vesicle fusion is monitored under whole-cell mode, the following applies; the subscript m denotes either patch or whole-cell characteristics. The input admittance before  $(Y_b)$ and after  $(Y_a)$  vesicle fusion differs.

$$
\mathbf{Y}_{\mathrm{b}} = [R_{\mathrm{s}} + \mathbf{Y}_{\mathrm{m}}^{-1}]^{-1} \tag{37}
$$

$$
\mathbf{Y}_{\rm a} = [R_{\rm s} + (\mathbf{Y}_{\rm m} + \mathbf{Y}_{\rm v})^{-1}]^{-1},\tag{38}
$$

where

$$
\mathbf{Y}_{\rm v} = \left[ R_{\rm p} + \frac{R_{\rm v}}{1 + j\omega R_{\rm v} C_{\rm v}} \right]^{-1} . \tag{39}
$$

Typically, access to the circuit parameters defining the vesicle admittance  $(Y_v: R_p, R_v, \text{ and } C_v; \text{ see Fig. 1 } B)$  is obtained experimentally by making an inescapable assumption – that at the onset of fusion  $R_s$ ,  $R_m$ , and  $C_m$  remain unchanged. Given the model, without this assumption estimates cannot be obtained with confidence.

The original and still common method to calculate vesicle parameters, including fusion pore conductance, employs capacitance compensation to estimate vesicle admittance (Breckenridge and Almers, 1987; Lindau, 1991; Ales et al., 1999). In this case, membrane admittance before fusion is removed by subtracting the  $Y_m$  baseline determined by capacitance compensation dithering (Neher and Marty, 1982); the subsequent change in admittance after vesicle fusion is used to calculate vesicle components based on a simplified vesicle circuit model of  $C_v$  in series with  $R_p$ (Breckenridge and Almers, 1987). We can employ the  $eCm$ method to arrive at  $Y_v$ , in a similar manner. First,  $Y_m$  is extracted from  $Y_{b}$ , the exact value of  $R_s$  having been obtained by analysis (see above) before fusion.

$$
\mathbf{Y}_{\mathrm{m}} = -\left[\frac{\mathbf{Y}_{\mathrm{b}}}{\mathbf{Y}_{\mathrm{b}}R_{\mathrm{s}} - 1}\right].\tag{40}
$$

Consequently, the vesicle admittance,  $Y_v$ , which includes the fusion pore, can be calculated (by substitution of Eq. 40 into Eq. 38) as a function of admittances measured before and after fusion,

$$
\mathbf{Y}_{\rm v} = \frac{R_{\rm s}^{-2}(\mathbf{Y}_{\rm b} - \mathbf{Y}_{\rm a})}{(R_{\rm s}^{-1} - \mathbf{Y}_{\rm b})(R_{\rm s}^{-1} - \mathbf{Y}_{\rm a})}.
$$
(41)

From inspection of the vesicle circuit (Fig. 1 B), it is clear that

$$
I_{\rm Rp} = I_{\rm Rv} + I_{\rm Cv},\tag{42}
$$

that is, we have the analogous circuit conditions that we analyzed above in the absence of fusion. The parameters  $R_p$ ,  $R_v$ , and  $C_v$  simply and, respectively, replace  $R_s$ ,  $R_m$ , and  $C_m$ . Using the same analysis logic as above, the magnitude and angle of  $\partial Y_v/\partial C_v$  is obtained, thus enabling the solution of all vesicle circuit parameters. The following equations detail fusion event analysis.

$$
C_{\rm v} = H_{\rm cv} \mathbf{B}_{\rm Yv} = \frac{\mathbf{B}_{\rm Yv}}{|\partial \mathbf{Y}_{\rm v}/\partial C_{\rm v}|} = \mathbf{B}_{\rm Yv} \frac{(1 + \omega^2 \tau_{\rm f}^2)}{\omega \left[1 - \frac{\tau_{\rm f}}{\tau_{\rm v}}\right]^2} \tag{43}
$$

$$
R_{\rm v} = \frac{\tau_{\rm v}}{C_{\rm v}} \tag{44}
$$

$$
R_{\rm p} = \frac{-\tau_{\rm f}\tau_{\rm v}}{C_{\rm v}(\tau_{\rm f} - \tau_{\rm v})},\tag{45}
$$

where

$$
\tau_{\rm f} = \left[ -\tan(\beta_{\omega v}) \pm \sqrt{1 + \tan(\beta_{\omega v})^2} \right] \omega^{-1} \tag{46}
$$

$$
\tau_{\rm v} = \frac{1 - \omega^2 \tau_{\rm f}^2 - 2\eta \omega \tau_{\rm f} \pm \left[ \sqrt{1 + \eta^2} + \sqrt{1 + \eta^2} \omega^2 \tau_{\rm f}^2 \right]}{\omega (-\eta + \eta \omega^2 \tau_{\rm f}^2 - 2\omega \tau_{\rm f})},\tag{47}
$$

and

$$
\eta = \tan \left[ 2 \tan^{-1} \left( \frac{\mathbf{B}_{\text{Yv}}}{\mathbf{A}_{\text{Yv}}} \right) \right]. \tag{48}
$$

### Simulations and biological cell examples

I provide several approaches to evaluate the  $eCm$  method of parameter estimation, including mathematical modeling, physical modeling, and tests on biological cells. It is important to realize that tests on biological cells may provide important information on real-world capabilities, but cannot be used to truly verify the validity of an approach. For example, it is impossible to know if a certain time course of  $C<sub>m</sub>$  change is truly occurring in cells, unless, of course, confirmation is obtained through other measures. However, physical and mathematical model evaluations can confirm validity of an approach, and do provide confidence that the results from biological cells are sound. In the first set of evaluations, MatLab (Natick, MA) was used to model the circuit admittance and implement  $eCm$  strictly in the frequency domain. In the following mathematical and physical simulations, measures were made at an  $f_0$  of 390.6 Hz and  $f_1$  of twice that, delivered simultaneously, unless otherwise noted. Amplitudes at each frequency were set equal, at 10–20 mV peak. Fig. 2 presents a simple whole-cell mathematical model simulation where the circuit parameters are stepped to evaluate component interactions on  $C<sub>m</sub>$ measures; comparisons are made of calculated component values using either the  $eCm$  method or other approaches that contain approximations. Clearly, eCm is superior, and is impervious to fluctuations in circuit component values. Fig. 3 presents another mathematical simulation in Matlab where vesicle fusion under whole-cell mode is evaluated, and compared with the standard methodology (Breckenridge and Almers, 1987; Lollike et al., 1995). Both methods are excellent even in the face of substantial  $R_s$  changes, but even with changes in vesicle resistance the  $eCm$  method produces an exact reconstruction of the model parameter changes. Although these model data highlight the exact nature of the eCm method, more demanding modeling efforts show the method's strengths. For the tests that follow, capacitance measures were obtained with  $eCm$  as implemented in the software package jClamp using a time resolution of 2.56 ms (i.e.,  $f_0$  of 390.6 Hz), unless otherwise noted.

Fig. 4 shows the results of a physical implementation of the simple model in Fig. 1 A under voltage clamp during a large step in capacitance, that was evoked by physically dislodging an additional capacitor that was placed parallel with  $C_m$ . Simultaneous measures of  $R_s$  and  $R_m$  remain essentially unperturbed. To evaluate large changes in  $R<sub>m</sub>$ , this parallel approach did not work because of associated parasitic capacitances of the large resistances involved. Instead, Fig. 5 shows two separate measures where all circuit and measurement details remained exactly the same except that either a 50-M $\Omega$  or 800-M $\Omega$  R<sub>m</sub> resistor was soldered into place. Again, there are minimal changes in  $C<sub>m</sub>$  measures. Fig. 6 shows the effects of maladjustments of the amplifier's fast capacitive compensation on parameter estimates. The model cell was measured over 10 seconds at a resolution of 2.56 ms while changes in compensation were made. Stray  $R_s$ capacitance of  $\pm 0.15$  pF had little effect on  $C_m$  ( $\pm 0.4\%$ ) or  $R_{\rm m}$  ( $\leq$  ±0.01%) parameter estimation.  $R_{\rm s}$  estimates varied  $±1.8%$ .

Finally, in Figs. 7 and 8 biological cells are investigated. Fig. 7 shows measures of outer hair cell (OHC) capacitance obtained with jClamp using a time resolution of 512  $\mu$ s. Detrending of data before analysis was performed (Santos-Sacchi, 2002). The rapid relaxation in capacitance during a step voltage change is due to the shift of the cell's nonlinear Q-V function along the voltage axis (Santos-Sacchi et al.,



FIGURE 2 Simulation of capacitance changes in whole-cell mode. The component values of the model ( $R_s$ : 10 M $\Omega$ ,  $R_m$ : 1 G $\Omega$ , and  $C_m$ : 6.5 pF) in Fig. 1 A were modulated out of phase with each other, with a  $C<sub>m</sub>$  jump of 0.05 pF accompanied by either a 600-M $\Omega$  drop in  $R<sub>m</sub>$ , or a 10-M $\Omega$  increase in  $R_s$  or all changes occurring simultaneously (see panels  $G-I$ ). The stimulating frequency  $f_0$  was the same for single-sine and  $eCm$  methods, with  $f_0$  at 390.6 Hz and  $f_1$  at twice that. In panels A–C, calculations are based on setting the PSD angle to an estimate (denoted by the prime) of  $\beta_{\omega}$ , the angle of  $\partial \mathbf{Y}/\partial G_s - 90^\circ$ ,  $\beta'_{\omega} = (2 \tan^{-1}(\mathbf{B}_Y/\mathbf{A}_Y) - 90^\circ)$ , to mimic  $R_s$ dithering. (A) A true piecewise linear approach was employed using this angle  $\beta'_{\omega}$  in place of  $\beta_{\omega}$  in Eq. 52. Whole-cell capacitance compensation was modeled by connecting and supplying the circuit components  $R_d$  and  $C_d$ (Fig. 1) with corresponding values of  $R_s$  and  $C_m$ , but with an overall negative admittance. PSD angle and gain corrections  $(1/abs(\partial \mathbf{Y}/\partial C_m))$  were determined from whole-cell conditions at the zero time point and remained fixed throughout. It can be seen that when cell components are changed  $(G-I)$  the phase angle changes causing errors in  $C<sub>m</sub>$  estimation (A). Even

1998). In that article, we confirmed through alternative measures that the time course of  $C<sub>m</sub>$  relaxation corresponded to the shift. The shift signifies the very rapid change in the gain of OHC electromotility, a process that likely drives the mammalian cochlear amplifier (Santos-Sacchi, 2003). The solid shaded line is a triple exponential fit to the data. The three time constants are 1.04, 5.96, and 36 ms. This time course is over an order of magnitude faster than has been previously reported (Santos-Sacchi et al., 1998). The substantial noise levels in this trace derive from the huge nonlinear capacitance  $(>=20 \text{ pF})$  and low input resistance  $(<$ 300 M $\Omega$ ) of the OHC. For comparison, Fig. 8 shows capacitance measures in a HEK cell transfected with prestin (Meltzer and Santos-Sacchi, 2001), where  $C_m$  noise was 5.5 fF (rms; 0.256 ms time resolution  $(f_0: 390.6 \text{ Hz})$ ; see discussion on noise effects below). This cell possesses a nonlinear  $Q_{\text{max}}$  (by fitting the Q-V curve with a two-state Boltzmann function (Santos-Sacchi, 1991b)) of 63.7 fC, giving rise to a peak voltage-dependent capacitance at -101 mV of 420 fF. The figure shows a 30-fF step in capacitance when voltage was stepped from  $+50$  mV to  $+30$  mV. These data indicate that the sensitivity of the  $eCm$  method is well within the range required for fusion event analysis.

though the PSD angle is set to guard against  $R_s$  changes, a change from 10 to 20 M $\Omega$  (I) is too large to counter; such overpowering effects of parameter changes are well known (Lindau, 1991). However, if capacitance compensation is not employed and point-by-point resetting of new angle and gain factors are made and applied, absolute  $C_m$  is obtained without any errors  $(B)$ . To make point-by-point corrections experimentally, the raw admittance  $(Y)$ at each point was taken and the angle of  $\beta'_{\omega}$  was calculated according to Zierler (1992), namely,  $\beta'_{\omega} = (2 \tan^{-1} (\mathbf{B}_Y / \mathbf{A}_Y) - 90^{\circ})$ . The true gain factor,  $H_c$ , at each data point was calculated as  $1/abs(\partial \mathbf{Y}/\partial C_m)$ . With each new gain and angle, circuit parameters were calculated as in Eq. 52, by extracting the component of  $Y$  at that phase angle and multiplying by that gain factor. Each admittance point was so treated to obtain circuit parameters. The reason this procedure works so well is that the value returned by this modified PSD analysis is the imaginary component of  $Y$ ; thus, this method produces the same results as the  $eCm$  method as shown in panel G. This useful single-sine approach, employing the estimate of  $H_c$  provided by Gillis (1995),  $H_c' = \omega/1 + \tan(\pi/2 - B_y)^2$ , is implemented in jClamp. However, because this is an estimate of the true gain,  $1/abs(\partial Y/\partial C_m)$ , relying on circuit approximations,  $C<sub>m</sub>$  estimates are not fully immune from circuit parameter changes. In panels  $D-F$ , calculations are based on setting the PSD angle to the angle of  $\partial Y/\partial C_m$ , namely  $\beta_{\omega}$ , to mimic capacitance compensation dithering. (D) The true piecewise linear approach was employed as above in panel A. In this case, using  $\beta_{\omega}$ , the large change in  $R_{\rm m}$  does not affect the phase angle substantially  $(F)$ , so  $C_m$  estimates are accurate and robust. However,  $R_s$  changes do interfere with angle and estimate, as expected (Joshi and Fernandez, 1988). Unlike the treatment above  $(B)$ , panel E shows that applying a point-by-point correction as detailed above to the uncompensated admittance fails to provide error free  $C<sub>m</sub>$  estimation, because the imaginary component of  $Y$  is not returned in this case. Panels  $G-I$  show the results of the  $eCm$  method, where the calculated absolute values are depicted by the circles. Note an exact correspondence between actual parameter values (solid lines) and calculated estimates  $(O)$ , with no parameter interactions. Simulation in MatLab.



FIGURE 3 Simulation and analysis of vesicle fusion event. Whole-cell conditions remained constant throughout simulation at  $R_m$ : 1 G $\Omega$ , and  $C_m$ : 6.5 pF, with  $R_s$ : 1, 10, and 20 M $\Omega$  for dark traces (vesicle resistance,  $R_v$ , held constant at 1 p $\Omega$  (1e15 $\Omega$ )). For the shaded trace,  $R_s$  was 1 M $\Omega$  and vesicle resistance,  $R_v$ , was stepped transiently from 1 p $\Omega$  to 10 G $\Omega$  as shown in panel G. (A, B) Imaginary and real components of admittance determined according to Breckenridge and Almers (1987). (C, D) Vesicle pore conductance and capacitance extracted from admittance using standard methodology (Breckenridge and Almers, 1987; Lollike et al., 1995). Note very good correspondence between components of model even when  $R_s$ changes substantially (solid lines in panels  $E, F$ ), but not when  $R_v$  is altered (shaded line). This discrepancy is not unanticipated because the standard methodology sets  $R_v$  as infinite (Breckenridge and Almers, 1987; Lollike et al., 1995).  $(E, F)$  Vesicle model parameters (solid lines) and estimates made with the  $eCm$  method ( $\bigcirc$ ). Correspondence is exact under all conditions. At time  $>5$ , vesicular fusion was simulated by linearly ramping the fusion pore resistance ( $R_p$ ; initially infinite) from 9 G $\Omega$  (111 pS) to 1 G $\Omega$ 



FIGURE 4 Effects of large  $C<sub>m</sub>$  changes on parameter estimates with the eCm method. Nominal initial component values of  $R_s$ : 10 M $\Omega$ ,  $R_m$ : 100 M $\Omega$ , and  $C_m$ : 33 pF || 15 pF. A step decrease in capacitance was accomplished by suddenly removing the parallel 15 pF component. The three panels show the calculated values of the parameters using the  $eCm$  method at a sampling rate of 2.56 ms. Note large abrupt drop in capacitance (top) with virtually no effect on measures of  $R_s$  and  $R_m$  (middle and bottom). Model was voltage clamped with a PC clone, Axon 200 amplifier (Union City, CA) in resistive feedback mode ( $\beta = 0.1$ ), 10-kHz Bessel filter, and Axon 1322A A/D D/A board.

# **DISCUSSION**

Three pieces of information are required to determine the circuit parameters,  $R_s$ ,  $R_m$ , and  $C_m$  of the traditional patchclamp-cell model circuit (Fig. 1 A). The typical information obtained in a one-frequency  $(\omega_0)$  measurement, namely, the real and imaginary components of the admittance, is insufficient. A third piece of information is required, and is usually obtained by exploring beyond  $\omega_0$ , that is, by utilizing information obtained at frequencies other than  $\omega_0$ . One popular solution is the "sine  $+dc$ " method (Pusch and Neher, 1988; Gillis, 2000), where a third piece of information, the input resistance  $(R_{\text{in}} = R_s + R_{\text{m}})$ , is extracted based on a priori knowledge of membrane reversal potential. This is basically a measurement at  $\omega_1 = 0$ . Alternatively, another non-dc piece of information, the admittance at  $\omega_1 > 0(\omega_1 \neq \omega_0)$  can be used to extract  $R_{\text{in}}$  (Santos-Sacchi et al., 1998; Santos-Sacchi, 2002). The latter approach benefits from statistical modeling to obtain an optimal result (Barnett and Misler, 1997). In this report, I have uncovered an additional piece of information at  $\omega_0$ , namely,  $\beta_\omega$ , which can be used to determine all circuit parameters. Despite the location of  $\beta_{\omega}$  precisely at  $\omega_0$ , the method does require two-frequency stimulation, and therefore analogous to the standard dual-sine method, it is

<sup>(1000</sup> pS); the resulting pore conductance is shown in panel  $F$  (solid line). Fusion event analysis was implemented at that time.



FIGURE 5 Effects of large  $R<sub>m</sub>$  changes on parameter estimates with the eCm method. Nominal component values of  $R_s$ : 10 M $\Omega$ ,  $R_m$ : 50 or 800 M $\Omega$ , and  $C_m$ : 15 pF. Note minimal interference with  $C_m$  and  $R_s$  estimates when a 50-M $\Omega$  resistor replaced the 800-M $\Omega$  resistor, other than changes in noise levels. PC clone, Axon 200 amplifier in capacitive feedback mode, 10-kHz Bessel filter, and Axon 1322A A/D D/A board were used.

reasonable to expect that optimal results could arise from further refinement (Barnett and Misler, 1997). I should also note that because  $\beta_{\omega}$  depends on  $\tau_{\text{clamp}}$ , an alternative approach would be fitting of current transients induced by step voltage commands. Of course, any method that does not measure  $\beta_{\omega}$  synchronously with the primary frequency component will be unable to correct for changes in cell parameters on a point-by-point basis. This will limit the utility of the technique, and this limitation is inherent in all "pause and dither" techniques. The  $eCm$  method benefits from point-by-point correction because gain and angle are redetermined and applied point-by-point at the  $f_0$  rate.

# Relation of the eCm method to traditional phase-tracking methods

The  $eCm$  method that I have developed here simply estimates absolute  $C_m$  by dividing the imaginary component of the input admittance  $(\mathbf{B}_{Y})$  at a single frequency by the



FIGURE 6 Effects of uncompensated stray capacitance on  $C_m$  measures with the  $eCm$  method. (A) Capacitive currents evoked by voltage step. Model  $R_s$  was in headstage but ungrounded. (Top) Fully compensated, (middle) undercompensated, and (bottom) overcompensated. The effect of these extremes was evaluated during parameter estimations after reassembly of the model circuit.  $(B)$  The three panels show model cell parameter estimates during manual under- and overcompensation of fast capacitance compensation.  $C_m$  was modulated  $\pm 0.3\%$ ;  $R_s$ ,  $\pm 1.8\%$ ; and  $R_m$ ,  $\leq \pm 0.01\%$ . The increase in  $C_m$  occurred during under compensation. Nominal component values of  $R_s$ : 10 M $\Omega$ ,  $R_m$ : 300 M $\Omega$ , and  $C_m$ : 18 pF.  $C_m$  noise: 14.6 fF rms; system noise with model 3.75 pA rms, 10-kHz Bessel filter, PC clone, Axon 200 amplifier in capacitive feedback mode, and Axon 1322A A/D D/A board.



FIGURE 7 Measurement of outer hair cell nonlinear capacitance with the  $eCm$  method. The rapid relaxation in capacitance during a step voltage change is due to the shift of the cell's nonlinear  $Q-V$  function along the voltage axis (Santos-Sacchi et al., 1998), and was confirmed through alternative measures. Cell was clamped with a PC clone, Axon 200B amplifier, 10-kHz Bessel filter, and Axon 1321A A/D D/A board with conditions described previously (Santos-Sacchi et al., 1998). See text for further details.

absolute value of the partial derivative  $\partial Y/\partial C_m$  at that same frequency. This method has an unforeseen relation to traditional phase-tracking techniques. The original phasetracking method was devised to account for and limit the effects of resistive components on  $C<sub>m</sub>$  measures (Neher and Marty, 1982; Joshi and Fernandez, 1988). It is a method that theoretically strives to determine  $C_m$  changes through measurement of changes in input admittance  $(\Delta Y)$  as a function of changes in the circuit parameter,  $C_{\text{m}}$ .

$$
\Delta I_{\rm Cm} \approx \partial \mathbf{Y} / \partial C_{\rm m} \, \Delta C_{\rm m} \, V \tag{49}
$$

$$
\Delta C_{\rm m} \approx \frac{1}{\partial \mathbf{Y}/\partial C_{\rm m}} \frac{\Delta I_{\rm cm}}{V} \tag{50}
$$

$$
\Delta C_{\rm m} \approx \frac{1}{|\partial \mathbf{Y}/\partial C_{\rm m}|} \operatorname{Re}\left[\frac{\Delta \mathbf{Y}}{e^{j\beta_{\omega}}}\right]
$$
(51)

$$
\Delta C_{\rm m} \approx H_{\rm c} \text{ Re}(\Delta \mathbf{Y} \ e^{-j\beta_{\omega}}). \tag{52}
$$

The latter equation is related to the nonsimplified form of Eq. 43 in Gillis (1995) and is addressed in a subsequent article of his (Gillis, 2000). However, heretofore, approximations of both  $\beta_{\omega}$  and  $H_c$  have only been possible. The benefits and drawbacks of using particular parameter approximations have been discussed in detail (Joshi and Fernandez, 1988). Thus, phase-tracking paradigms that use estimates of the magnitude and angle of  $\partial Y/\partial C_m$  are recognized as better suited to systems where  $R_s$  is stable and  $R<sub>m</sub>$  may fluctuate (Joshi and Fernandez, 1988). However, where the resistive components have the converse behavior, the angle of  $\partial \mathbf{Y}/\partial G_s - 90^\circ$ , namely, 2 tan<sup>-1</sup> (**B**<sub>Y</sub>/



FIGURE 8 Measurement of capacitance step in prestin transfected HEK cell. Under voltage clamp a step voltage from  $+50$  mV to  $+30$  mV evoked a step increase in capacitance of 30 fF.  $C<sub>m</sub>$  noise: 5.5 fF rms. PC clone, Axon 200B amplifier in resistive feedback mode, 10-kHz Bessel filter, and National Instruments (Austin, TX) PCI-6052E A/D D/A board were used.

 $A_Y$ ) – 90 $\degree$  as nicely provided by Zierler (1992), may be a better choice (Joshi and Fernandez, 1988). Unfortunately, where both resistive components simultaneously fluctuate, phase tracking is problematic. Despite these caveats, and even with the correct quantities I now provide, implementation of the phase tracking either by feeding the raw current output of the patch clamp into a hardware lock-in amplifier or a software phase detector (PSD) appears to be an inappropriate implementation of the phase analysis concept (Joshi and Fernandez, 1988; Neher and Marty, 1982; Fidler and Fernandez, 1989). That is, if the analyzed signal is  $Y$ , then in contradistinction to Eq. 52,

$$
\Delta C_{\rm m} \neq H_{\rm c} \operatorname{Re}(\mathbf{Y} \, e^{-j\beta_{\omega}}). \tag{53}
$$

Consequently, the result of evaluating Y (or  $I_{\rm Rs}$ ) directly should not provide an accurate picture of changes in  $C_m$  (i.e.,  $\Delta C_{\text{m}}$ ).

The surprising fact is, however, that implementations using direct evaluations of  $Y$  can, under certain conditions, provide very good estimates of absolute  $C_{\text{m}}$ .

It should be noted that applying capacitance and series resistance compensation at the onset of an experiment cannot be construed as providing a  $\Delta I_{\rm Rs}$  (i.e.,  $\Delta$ **Y** V) output from the amplifier. This is simply a one-time subtraction that would have to be repeated, along with a new angle determination, every time a data point is collected. Additionally, only a twoelement model is used by amplifiers for such compensation.

One reason for success with this direct approach would be if  $R_s$  were very small, i.e., as  $R_s$  approaches zero,  $\beta_{\omega} \approx \Phi = 90^{\circ}$ , and absolute values of  $I_{\rm Cm}$  will be evaluated. Unfortunately, it is unlikely that  $R_s$  will be so low (and maintained so low) so as to approach this condition. Notwithstanding this apparent quandary, it is possible to implement phase-tracking paradigms with direct evaluations of Y and still obtain excellent estimates of  $C_m$  in the face of very large changes in  $R_s$  and  $R_m$ . Surprising, the angle returned by series resistance dithering works better than that returned by capacitance compensation dithering.

### Series resistance dithering

Dithering of the series resistance, championed by Joshi and Fernandez (1988), is used to return a close approximation of  $\beta_{\omega}$ , namely  $\angle \partial Y/\partial G_s - 90^\circ$ . This approximation, however, when used with a direct analysis of Y, rather than  $\Delta Y$ , and point-by-point (i.e., real time) gain and angle correction is surprisingly exact (see the simulations in Fig.  $2 B$ ). The outcome of such an implementation does not suffer from the caveats normally expected with the phase-tracking approach (Joshi and Fernandez, 1988)—namely, large changes in  $R<sub>m</sub>$ (or  $R_s$ ) have no effect on the measure of  $C_m$ . The reason for this is because the angle of  $\partial$ Y/ $\partial$ G<sub>s</sub> is twice the angle of Y (Zierler, 1992), and the PSD measurements are simply returning  $\mathbf{B}_{\Upsilon}$ ,

$$
\mathbf{B}_{\mathbf{Y}} = Im(\mathbf{Y}) \tag{54}
$$

$$
\mathbf{B}_{\mathrm{Y}} = Re[\mathbf{Y} \, \boldsymbol{e}^{-\mathrm{j}(\angle \partial \mathbf{Y}/\partial \mathbf{G}_{\mathrm{s}} - \pi/2)}] = Re[\mathbf{Y} \, \boldsymbol{e}^{-\mathrm{j}(2\angle \mathbf{Y} - \pi/2)}]. \tag{55}
$$

Thus, whereas Eq. 53 fails to provide  $\Delta C_{\text{m}}$  estimates, simply replacing the angle  $\angle \partial Y/\partial C_m$  with  $\angle \partial Y/\partial G_s$ - $90^{\circ}$  results in an exact solution for absolute  $C_{\rm m}$ , as shown previously in Eq. 26,

$$
C_{\rm m} = H_{\rm c} \, \mathbf{B}_{\rm Y} = H_{\rm c} \, Re[\mathbf{Y} \, e^{-\mathrm{j}(\angle \partial \mathbf{Y}/\partial G_{\rm s} - \pi/2)}]. \tag{56}
$$

Any complex number can be evaluated at twice its angle to return its real component and at twice its angle  $-90^{\circ}$  to return its imaginary component. Thus, in this case, it turns out that the  $eCm$  method is simply being employed.

### Capacitance compensation dithering

The initial work of Neher and Marty (1982) utilized capacitance compensation dithering to obtain an angle at which to evaluate, via PSD, changes in  $C<sub>m</sub>$ . The angle provides an excellent approximation of  $\beta_{\omega}$  when capacitance

compensation is in effect. This is shown by inspection of  $\partial Y$ /  $\partial C_d$  and its angle, based on the model of Fig. 1 A, now including the capacitance compensation components  $C_d$  and  $R_d$  (in series with each other, from headstage to ground).

$$
\frac{\partial \mathbf{Y}}{\partial C_{d}} = \frac{-j\omega}{\left(R_{d}C_{d}\omega - j\right)^{2}}
$$
(57)

$$
\angle \partial \mathbf{Y} / \partial C_{d} = -\tan^{-1} \left[ \frac{\omega^{2} \tau_{d}^{2} - 1}{2 \omega \tau_{d}} \right],
$$
 (58)

where  $\tau_d = R_d C_d$ .

 $\beta_{\omega}$ , the angle of  $\partial Y/\partial C_{\text{m}}$ , remains unaffected by the addition of the capacitance compensation circuitry,

$$
\beta_{\omega} = -\tan^{-1} \left[ \frac{\omega^2 \tau_{\text{clamp}}^2 - 1}{2\omega \tau_{\text{clamp}}} \right],\tag{59}
$$

thus indicating that when the clamp time constant  $(\tau_{\text{clamp}})$ and compensation time constant  $(\tau_d)$  are equal, i.e., when compensation is in effect, the angle returned by dithering equals  $\beta_{\omega}$ . Unlike the use of the angle returned by series resistance dithering, the use of this angle to measure  $C_m$  with direct evaluations of Y is not as accurate (Fig.  $2 E$ ). It should be noted that these analyses only apply to direct measures of Y that are corrected on a point-by-point basis for phase and gain changes, and not necessarily to the traditional use of the angle (Neher and Marty, 1982).

## Validity, accuracy, and sensitivity of  $C<sub>m</sub>$ measurement methods

There are several factors, including model validity, approximations, and noise that contribute to errors in the measurement of capacitance with sinusoidal analysis. Obviously, approximations lead to errors only if they fail; however, because approximations often remove a particular component, e.g.,  $R_s$  or  $R_v$ , from the system of equations, it is impossible to gauge failure during an experiment. Thus, it is prudent to make as few simplifications and approximations as possible. The mathematical and physical modeling that I have presented clearly indicate that the eCm method benefits from this rule.

Noise, on the other hand, is an issue that affects all electrical measures of cell activity regardless of the method's validity. Even for a method that provides a valid measure of some electrical quantity in the absence of noise, the introduction of noise can prove devastating, or at least render it useless for a given task. Not surprisingly, some methods may be able to deal with system noise better than others.

The design of sinusoidal stimulus protocols has enormous impact on  $C_m$  measurement sensitivity in the face of realworld noise. Important issues such as stimulus frequency,

stimulus magnitude, stray capacitance, and unexpected conductance changes have been discussed in detail (Gillis, 1995; Barnett and Misler, 1997; Thompson et al., 2001; Debus et al., 1995). Careful attention to these issues can lead to incredible sensitivity; for example, with very highfrequency stimulation and very large voltages, very good signal/noise ratios can be obtained, providing noise floors well below 1 fF (Klyachko and Jackson, 2002). One of the consequences of the equivalency between the  $eCm$  method and the phase-tracking method as typically employed, is that effects of noise on performance might be expected to be similar for each method. To evaluate issues like this, comparisons were made under varying noise conditions in model simulations.

In Fig. 9, a modeling approach is used to compare the effects of Gaussian noise levels on  $C<sub>m</sub>$  estimate noise among a few common methods of  $C_m$  estimation. In this approach, the simple circuit of Fig. 1 A was modeled in the time domain using the RK4 method hardcoded in C within jClamp; the results were then independently analyzed by transient step analysis, single-sine analysis, dual-sine analysis, or the  $eCm$ method. Step analysis follows the method outlined in a prior publication (see appendix in Huang and Santos-Sacchi,



FIGURE 9 Effect of system noise on  $C_m$  estimate noise. Results from either mathematical modeling (lines) or physical modeling (symbols). Three methodologies, step (*dashed line*,  $\nabla$ *)*, *eCm* (*dash-dotted line*,  $\triangle$ *)*, and single-sine phase tracking (solid line,  $\blacksquare$ ) are presented. For the software model, forced Gaussian noise levels were imposed, and the noise of  $C<sub>m</sub>$ estimates calculated. For the physical model, system noise levels were 3.8 pA rms when the model was attached to the headstage. To obtain lower system noise levels, averaging was performed to produce the plotted noise levels. For the electrical model, a 10-kHz Bessel filter was used, and the frequency components of the remaining noise were likely different from the wideband noise used for the math model. This likely accounts for differences in math and electrical model results. In any case, the data from each model indicate that as system noise decreases, all of the methods become comparable. Nominal component values of  $R_s$ : 10 M $\Omega$ ,  $R_m$ : 300 M $\Omega$ , and  $C_m$ : 18 pF. IBM T40 laptop in battery mode (Armonk, NY), Axon 200 amplifier in capacitive feedback mode, 10-kHz Bessel filter, and Quatech (Hudson, OH) DAQP 308 PCMCIA PC card A/D D/A board were used.

1993). Such an analysis is multifrequency, providing extended information similar to that obtained from ''chirp'' stimuli (Santos-Sacchi, 1991b; Santos-Sacchi, 1989), and wideband noise stimuli (Fernandez et al., 1982). Features of our step method included automatic clocking to reach steady state and utilization of exponential fitting after the initial onset transient, methodology recently reemphasized as important for the robust use of transient analysis for  $C<sub>m</sub>$ measurement (Thompson et al., 2001). In our original implementation and in jClamp, a correction for errors introduced by the  $R_s/R_m$  voltage divider on Q, namely that  $C_m = (R_m + R_s)^2 / R_m^2 Q / V_m$ , is employed (Huang and Santos-Sacchi, 1993). To my knowledge, no other implementation accounts for this potential error. Single-sine analysis follows the approximation (for  $\beta_{\omega}$  and  $H_c$ ) method outlined in the Fig. 2 legend. The dual-sine method (Santos-Sacchi, 1992; Santos-Sacchi et al., 1998), follows the same fast Fourier transform-based determination of the real and imaginary components employed by the  $eCm$  method. In both cases estimates derived from both  $\omega_0$  and  $\omega_1$  are averaged ( $f_0$ : 390.6 Hz;  $f_1$ : 781.2 Hz). This averaging benefit must be kept in mind when comparing single-sine estimates. All methodologies are standard features in jClamp. In Fig. 9 the relation between measured  $C<sub>m</sub>$  noise and imposed current noise is examined for each of the methodologies with either a 100-M $\Omega$  or 500-M $\Omega$  R<sub>m</sub>. All methods work well under low-noise conditions, and this simply indicates that the true limitation for  $C_m$  estimation is the noise of the system at those frequencies used by the method. Indeed, under realworld conditions where system noise levels are well minimized, step, single-sine and dual-sine techniques can provide roughly equivalent  $C_m$  estimate noise levels (within  $\pm 10$ –30%) close to theoretical limits (Gillis, 1995; Barnett and Misler, 1997; Thompson et al., 2001). However, under forced noise levels as in Fig. 9 the  $eCm$  and single-sine techniques appear better able to deal with higher noise levels than this step implementation. Because of the exact same implementation of frequency analysis and the absence of approximations for  $eCm$  and dual-sine approaches, sensitivities turn out to be essentially equivalent. Had  $\beta_{\omega}$  been determined in another manner, e.g., by the  $d\omega$  approach, the results may have differed. Given the relation between the single-sine phase-tracking approach and the  $eCm$  method detailed above, it is not surprising that these two methods are roughly equivalent in handling noise. For each method, slightly better noise levels are achieved when  $\beta_{\omega}$  is fixed during analysis to simulate a ''pause and dither'' approach; thus, recalculating  $\beta_{\omega}$  for each sample introduces additional noise in the analysis that must be balanced with the increased validity afforded by point-by-point correction. The step analysis is particularly prone to high noise levels; this is especially obvious when low frequency (e.g., 60 Hz) interference is included, and is in marked contrast to sinusoidal approaches that can avoid extraneous spectral interference. The conclusions based on this mathematical modeling effort were essentially confirmed with a physical implementation (see Fig. 9). From these results, it is clear that given a sufficiently low system noise or actually a sufficiently high signal/noise level, the  $eCm$  method will have the sensitivity to analyze fusion events, as clearly suggested by the physiological results shown in Fig. 8.

# SUMMARY

The new  $eCm$  method that I outlined here provides another tool for analysis of cellular processes that can be interrogated by  $C_m$  measures. It is a method that works in the absence of usual simplifying assumptions and approximations of the traditional patch-clamp-cell model circuit. In detailing the approach, several new observations have been made. They include: 1), the imaginary component of the input admittance Y, namely,  $\mathbf{B}_{Y}$ , can be worked on by  $\partial \mathbf{Y}/\partial C_{m}$  to obtain absolute values of  $C_m$ ; 2), the angle of  $\partial \mathbf{Y}/\partial C_m$ , namely,  $\beta_\omega$ , is the same as that of  $\frac{\partial \mathbf{Y}}{\partial \omega}$  and therefore can be obtained from frequency manipulation alone; 3), given  $\beta_{\omega}$ , the absolute value of  $\partial Y/\partial C_m$  can be determined; 4), frequency manipulation need not require an infinitesimal  $d\omega$  to extract  $\beta_{\omega}$ ; and 5), the traditional phase-tracking technique that evaluates raw amplifier currents, rather than difference currents, at the angle provided by series resistance dithering, works similar to the  $eCm$  method by simply returning estimates of  $\mathbf{B}_{\text{Y}}$ , not  $\Delta I_{\text{Cm}}$ , and ultimately provides absolute, not delta,  $C_m$  estimates. Finally, it might be expected that enhancements of the  $eCm$  technique may arise from future implementations in hardware and by statistical optimizations.

I thank Peter Dallos, Fred Sigworth, and Alan Segal for looking at early drafts. I especially thank Peter Dallos for confirming some of the concepts presented in the manuscript, and identifying others that needed rethinking. Finally, I thank the reviewers for many helpful suggestions.

This work was supported in part by the National Institutes of Health (National Institute on Deafness and Other Communication Disorders grant no. DC00273).

# **REFERENCES**

- Ales, E., L. Tabares, J. M. Poyato, V. Valero, M. Lindau, and D. T. Alvarez. 1999. High calcium concentrations shift the mode of exocytosis to the kiss-and-run mechanism. Nat. Cell Biol. 1:40–44.
- Alvarez De Toledo, G. A., R. Fernandez-Chacon, and J. M. Fernandez. 1993. Release of secretory products during transient vesicle fusion. Nature. 363:554–558.
- Aravanis, A. M., J. L. Pyle, and R. W. Tsien. 2003. Single synaptic vesicles fusing transiently and successively without loss of identity. Nature. 423:643–647.
- Barnett, D. W., and S. Misler. 1997. An optimized approach to membrane capacitance estimation using dual-frequency excitation. Biophys. J. 72: 1641–1658.
- Bigiani, A., and S. D. Roper. 1995. Estimation of the junctional resistance between electrically coupled receptor cells in Necturus taste buds. J. Gen. Physiol. 106:705–725.
- Breckenridge, L. J., and W. Almers. 1987. Currents through the fusion pore that forms during exocytosis of a secretory vesicle. Nature. 328:814–817.
- Cole, K. S. 1971. Some aspects of electrical studies of the squid giant axon membrane. In Biophysics and Physiology of Excitable Membranes. W. J. Adelman, editor. Van Nostrand Reinhold Co., New York. 125–42.
- Debus, K., J. Hartmann, G. Kilic, and M. Lindau. 1995. Influence of conductance changes on patch clamp capacitance measurements using a lock-in amplifier and limitations of the phase tracking technique. Biophys. J. 69:2808–2822.
- Debus, K., and M. Lindau. 2000. Resolution of patch capacitance recordings and of fusion pore conductances in small vesicles. Biophys. J. 78:2983–2997.
- Fernandez, J. M., F. Bezanilla, and R. E. Taylor. 1982. Distribution and kinetics of membrane dielectric polarization. II. Frequency domain studies of gating currents. J. Gen. Physiol. 79:41–67.
- Fidler, N., and J. M. Fernandez. 1989. Phase tracking: an improved phase detection technique for cell membrane capacitance measurements. Biophys. J. 56:1153–1162.
- Fricke, H. 1925. The electric capacity of suspensions with special reference to blood. J. Gen. Physiol. 9:137–152.
- Gandhi, S. P., and C. F. Stevens. 2003. Three modes of synaptic vesicular recycling revealed by single-vesicle imaging. Nature. 423:607–613.
- Gillis, K. D. 1995. Techniques for membrane capacitance measurements. In Single-Channel Recording. B. Sakmann and E. Neher, editors. Plenum Press, New York. 155–98.
- Gillis, K. D. 2000. Admittance-based measurement of membrane capacitance using the EPC-9 patch-clamp amplifier. Pflugers Arch. 439:655-664.
- Huang, G., and J. Santos-Sacchi. 1993. Mapping the distribution of the outer hair cell motility voltage sensor by electrical amputation. Biophys. J. 65:2228–2236.
- Jaffe, L. A., and L. C. Schlichter. 1985. Fertilization-induced ionic conductances in eggs of the frog, Rana pipiens. J. Physiol. 358:299–319.
- Joshi, C., and J. M. Fernandez. 1988. Capacitance measurements. An analysis of the phase detector technique used to study exocytosis and endocytosis. Biophys. J. 53:885–892.
- Klyachko, V. A., and M. B. Jackson. 2002. Capacitance steps and fusion pores of small and large-dense-core vesicles in nerve terminals. Nature. 418:89–92.
- Lindau, M. 1991. Time-resolved capacitance measurements: monitoring exocytosis in single cells. Q. Rev. Biophys. 24:75–101.
- Lindau, M., and E. Neher. 1988. Patch-clamp techniques for time-resolved capacitance measurements in single cells. Pflugers Arch. 411:137–146.
- Lollike, K., N. Borregaard, and M. Lindau. 1995. The exocytotic fusion pore of small granules has a conductance similar to an ion channel. J. Cell Biol. 129:99–104.
- Meltzer, J., and J. Santos-Sacchi. 2001. Temperature dependence of nonlinear capacitance in human embryonic kidney cells transfected with prestin, the outer hair cell motor protein. Neurosci. Lett. 313:141–144.
- Neher, E., and A. Marty. 1982. Discrete changes of cell membrane capacitance observed under conditions of enhanced secretion in bovine adrenal chromaffin cells. Proc. Natl. Acad. Sci. USA. 79:6712–6716.
- Oppenheim, A., and R. Schafer. 1975. Digital Signal Processing. Prentice-Hall, Englewood Cliffs, NJ
- Pusch, M., and E. Neher. 1988. Rates of diffusional exchange between small cells and a measuring patch pipette. *Pflugers Arch*. 411:204-211.
- Ratinov, V., I. Plonsky, and J. Zimmerberg. 1998. Fusion pore conductance: experimental approaches and theoretical algorithms. Biophys. J. 74:2374–2387.
- Sakmann, B., and E. Neher. 1995. Geometric parameters of pipettes and membrane patches. In Single-Channel Recording. B. Sakmann and E. Neher, editors. Plenum Press, New York. 637–50.
- Santos-Sacchi, J. 1989. Asymmetry in voltage-dependent movements of isolated outer hair cells from the organ of Corti. J. Neurosci. 9:2954– 2962.
- Santos-Sacchi, J. 1991a. Isolated supporting cells from the organ of Corti: some whole cell electrical characteristics and estimates of gap junctional conductance. Hear. Res. 52:89–98.
- Santos-Sacchi, J. 1991b. Reversible inhibition of voltage-dependent outer hair cell motility and capacitance. J. Neurosci. 11:3096–3110.
- Santos-Sacchi, J. 1992. On calculating series resistance: step and two-sine approaches. Poster presentation at the Yale Neuroscience Retreat, Feburary 21–23. Marine Biological Laboratory, Woods Hole, MA.
- Santos-Sacchi, J. 2002. Scisoft Technical Note. http://www.scisoftco.com/ detrending\_for\_2\_sine\_cm\_measures.pdf.
- Santos-Sacchi, J. 2003. New tunes from Corti's organ: the outer hair cell boogie rules! Curr. Opin. Neurobiol. 13:459–468.
- Santos-Sacchi, J., S. Kakehata, and S. Takahashi. 1998. Effects of membrane potential on the voltage dependence of motility-related charge in outer hair cells of the guinea-pig. J. Physiol. 510:225–235.
- Thompson, R. E., M. Lindau, and W. W. Webb. 2001. Robust, highresolution, whole cell patch-clamp capacitance measurements using square wave stimulation. Biophys. J. 81:937–948.
- Zhao, H. B., and J. Santos-Sacchi. 1998. Effect of membrane tension on gap junctional conductance of supporting cells in Corti's organ. J. Gen. Physiol. 112:447–455.
- Zhao, H. B., and J. Santos-Sacchi. 1999. Auditory collusion and a coupled couple of outer hair cells. Nature. 399:359–362.
- Zierler, K. 1992. Simplified method for setting the phase angle used in capacitance measurements in studies of exocytosis. Biophys. J. 63: 854–856.